

High Efficiency Off-Line CC/CV Switch

FEATURES

- Constant-Current (CC) and Constant-Voltage (CV) with Primary Side Control
- Proprietary technology enabling high efficiency and fast dynamic response
- No audible noise over entire operating range
- Built-in power MOS
- Built-in Cable Compensation
- Built-in Line Compensation
- Primary-side feedback eliminates opto-coupler and TL431
- Cycle-by-Cycle Current Limiting
- Over Temperature Protection
- VCC Over Voltage Protection
- CV Open-loop Protection
- Excellent capacitive loading start-up performance

TYPICAL APPLICATION

- Adapter/Charger for Cell/Cordless Phones, PDAs, MP3 and Other Portable Apparatus
- Standby and Auxiliary Power Supplies Set Top Boxes (STB)
- Adapter for ADSL / WiFi Wireless
- AC/DC LED Driver applications

DESCRIPTION

The FT838MBD/FT838MDD controller device is optimized for high-performance, low power switching mode power supply applications. The FT838MBD/FT838MDD facilitates CC/CV charger design by eliminating an opto-coupler and TL431. Its highly integrated functions such as Under Voltage Lockout (UVLO), Leading Edge Blanking (LEB) and built-in cable compensation offer the users a high efficiency and low cost solution for AC/DC power applications.

Power supplies built with FT838MBD/FT838MDD can achieve both high average efficiency, fast dynamic load response and super low standby power.

Furthermore, FT838MBD/FT838MDD features fruitful protections like Open Circuit Protection and Over Temperature Protection to eliminate the external protection circuits and provide reliable operations. FT838MBD/FT838MDD is available in DIP8 package.

TYPICAL APPLICATION CIRCUIT

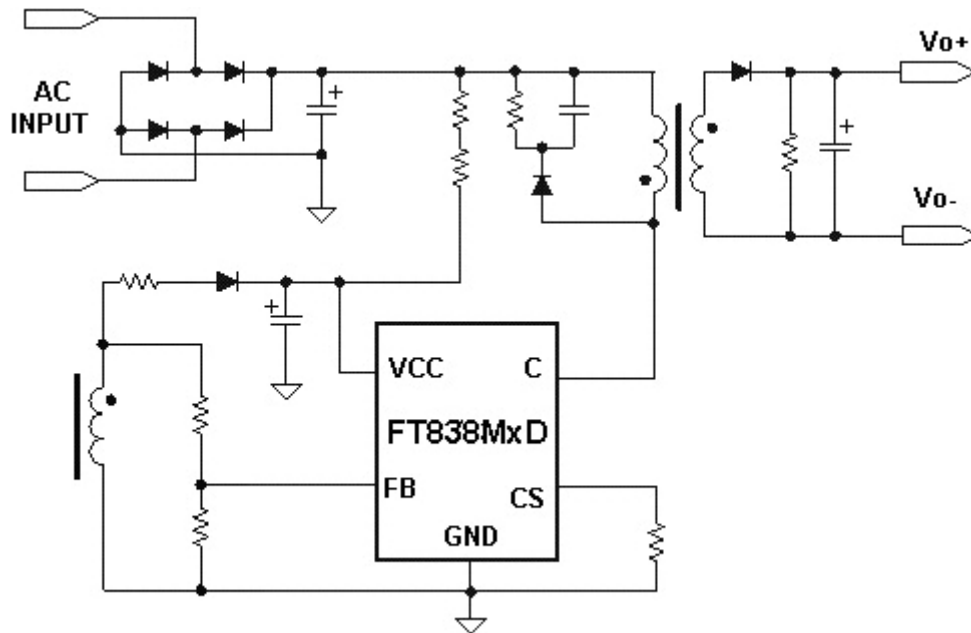


Figure 1: FT838MBD/838MDD Typical Application Circuit

ABSOLUTE MAXIMUM RATINGS

| | |
|----------------------------------|-----------------|
| FB to GND..... | -0.3V to +7V |
| CS to GND..... | -0.3V to +7V |
| VCC to GND..... | -0.3V to +30V |
| C to GND..... | -0.3V to +700V |
| Operating Temperature Range..... | -40°C to +125°C |
| Junction Temperature..... | -40°C to +150°C |
| Storage Temperature Range | -60°C to +150°C |
| ESD Protection HBM..... | 2000V |
| ESD Protection MM..... | 200V |

***Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.**

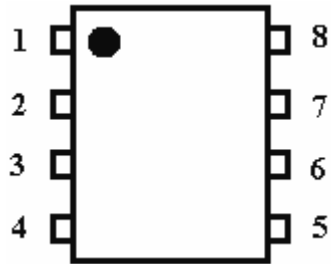
PIN CONFIGURATION

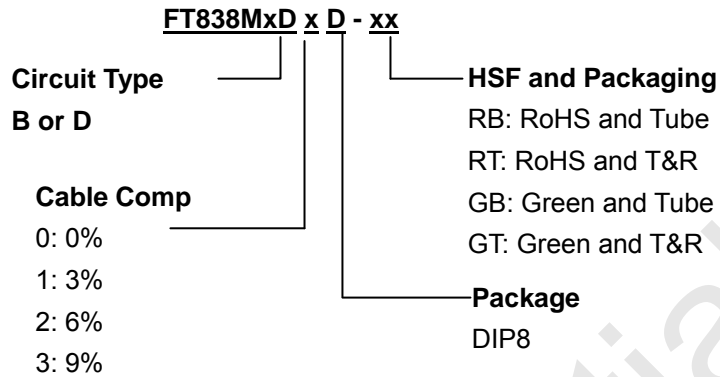
Figure 2: Pin Assignments

TERMINAL DEFINITION

| Pin | Name | Description |
|-----|------|--|
| 1 | CS | Primary current sense |
| 2 | FB | Output voltage feedback pin |
| 3 | GND | Ground. |
| 4 | VCC | Supply voltage |
| 5 | NC | No connection |
| 6 | | |
| 7 | D | The drain of the power MOS. This pin is connected to the primary lead of the transformer |
| 8 | | |

Table 1

ORDERING INFORMATION



FT838MBD^①/FT838MDD^①

| Device | DESIGNATOR | SYMBOL | Options |
|--|------------|--------|-----------------|
| FT838MBD ^① FT838MDD ^① | ① | 0 | Cable Comp = 0% |
| | | 1 | Cable Comp = 3% |
| | | 2 | Cable Comp = 6% |
| | | 3 | Cable Comp = 9% |

Table 2

MARKING RULE

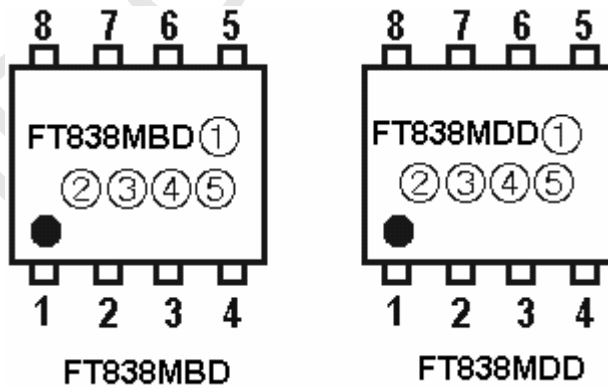


Figure 3: Marking Rule

- ①: Represents Version (0, 1, 2 or 3)
- ②③④⑤: for internal reference

Block Diagram

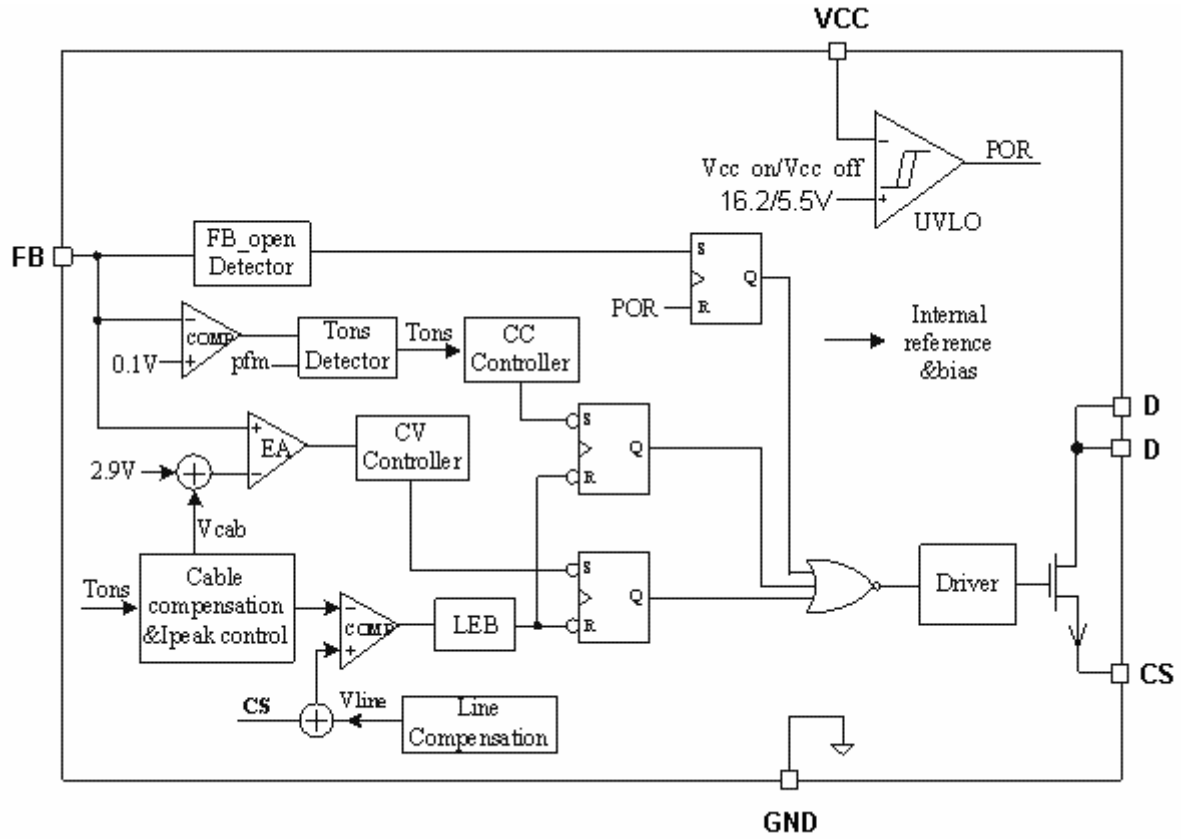


Figure 4: FT838MBD/838MDD Block Diagram

ELECTRICAL CHARACTERISTICS

(For typical values Tj=25°C, Vcc=12V, unless otherwise noted)

| Characteristic | | Symbol | Min | Typ | Max | Unit |
|--|--------------------|--|-------|------|-------|------|
| Current Sense | | | | | | |
| Maximum Current Threshold | | Vcs_max | 535 | 552 | 575 | mV |
| Leading Edge Blanking Duration | | Tleb | 350 | 400 | 450 | ns |
| Propagation Delay (OUT=1.0nF to GND) | | Tpd | | | 200 | ns |
| Feedback Section | | | | | | |
| Feedback Voltage Threshold | | Vfb | 2.856 | 2.9 | 2.944 | V |
| CCM protection Threshold Level | | Vcp | | 100 | | mV |
| Supply Section | | | | | | |
| Start Up Threshold Voltage | | Vcc_on | 15.5 | 16.2 | 17.5 | V |
| Under Voltage Lockout Voltage | | Vcc_off | 5.2 | 5.5 | 6.0 | V |
| VCC Start Up Current | | Istart_up | | 2 | 5 | uA |
| Operating Current | | Iop | 0.4 | 0.5 | 0.7 | mA |
| Protection Section | | | | | | |
| Feedback Loop Open Protection | | Ifb_open | 90 | 115 | 140 | uA |
| VCC Over Voltage Protection | | Vcc_OVP | 26 | 27 | 28 | V |
| Over Temperature Protection | | T_OTP | | 145 | | °C |
| Compensation | | | | | | |
| Line Compensation (I _{fb} =1mA) | | Vline | 25 | 33 | 40 | mV |
| Cable compensation | 0 | Kcab | | 0 | | % |
| | 1 | | | 3 | | |
| | 2 | | | 6 | | |
| | 3 | | | 9 | | |
| Power MOS Section (FT838MBD) | | | | | | |
| Characteristic | Symbol | Test condition | Min | Typ | Max | Unit |
| Static drain-source on-resistance | R _{DS_ON} | V _{GS} =10V, I _{DS} =0.5A | | 5.5 | | Ω |
| Drain-source breakdown voltage | BV _{DSS} | V _{GS} =0V, I _{DS} =250uA | 650 | | | V |
| Drain-source leakage current | I _{DSS} | V _{GS} =0V, V _{DS} =650V | | | 10 | uA |
| Maximum Drain Current | I _{DMAX} | V _d =4V | 0.6 | 0.7 | | A |
| Power MOS Section (FT838MDD) | | | | | | |
| Static drain-source on-resistance | R _{DS_ON} | V _{GS} =10V, I _{DS} =0.5A | | 2.6 | | Ω |
| Drain-source | BV _{DSS} | V _{GS} =0V, | 650 | | | V |

| | | | | | | |
|------------------------------|------------|-------------------------------|-----|-----|----|---------|
| breakdown voltage | | $I_{DS}=250\mu A$ | | | | |
| Drain-source leakage current | I_{DSS} | $V_{GS}=0V,$ $V_{DS}=650V$ | | | 10 | μA |
| Maximum Drain Current | I_{DMAX} | $V_d=3V$ | 1.0 | 1.1 | | A |

Table 3

FUNCTIONAL DESCRIPTION**Operating Description**

FT838MBD/FT838MDD is a cost effective and high-performance AC-DC power supply controller for off-line low power AC-DC applications including battery chargers, adaptors and LED lighting. The constant voltage (CV) and constant current (CC) control are achieved accurately without the secondary feedback circuit.

Start up Control

Start-up current of FT838MBD/838MDD is very low so that a start-up resistor with high resistance and low-wattage is allowed to supply the start-up power for the controller. The large value startup resistor minimizes the power loss in operations and allows quick start up. With a special fast startup technology, FT838MBD/FT838MDD starts up easily in capacitive loading applications.

Operating current

The operating current of FT838MBD/FT838MDD is as low as 500uA. Good efficiency is achieved with the low operating current. Low operating current also reduces the Vcc hold-up capacitance requirement.

Constant voltage (CV) and constant current (CC) Operation

The FT838MBD/FT838MDD can accurately achieve CV/CC characteristic output without secondary side voltage and current-feedback circuits. It operates in CV mode to regulate the output voltage by capturing the auxiliary winding feedback voltage at FB pin. The auxiliary winding feedback voltage is proportional to secondary winding, so it provides controller the feedback signal from secondary side and achieves constant-voltage output. In CC mode, the controller detects the secondary discharger peak current and the discharger time, which determines the off-time of the base driver to make the output average current constant.

Primary peak current modulation

Primary peak current is constant at constant current mode. And primary peak current is modulated at constant voltage mode for the purposes of good dynamic load response and no audible noise over entire operating range. According to the output loading current the current threshold voltage is modulated from 0.55V to 0.27V. The current threshold voltage is 0.55V at rated load and 0.27V at light load.

Leading edge blanking

Each time the power MOS transistor is switched on, a turn-on spike occurs at the sense resistor. To avoid premature termination of the switching pulse, a 400ns leading edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current limit comparator is disabling and cannot switch off the base driver.

Under voltage lockout (UVLO)

FT838MBD/FT838MDD turn-on Vcc_on and turn-off Vcc_off are 16.2 V and 5.5 V, respectively. During start-up, the hold-up capacitor must be charged to 16.2V through the start-up resistor. The hold-up

capacitor continues to supply V_{cc} until power can be delivered from the auxiliary winding of the transformer. V_{cc} must not drop below 5.5 V during this start-up process. This UVLO hysteresis window ensures that hold-up capacitor is sufficient to supply V_{cc} during start-up.

Protection control

With rich protection features of FT838MBD/FT838MDD, excellent power supply system reliability can be achieved. The protection features include cycle by cycle current limiting, V_{cc} over voltage protection and clamp, over temperature protection, feedback loop open circuit protection and V_{cc} under voltage lockout, etc.

Integrated MOS

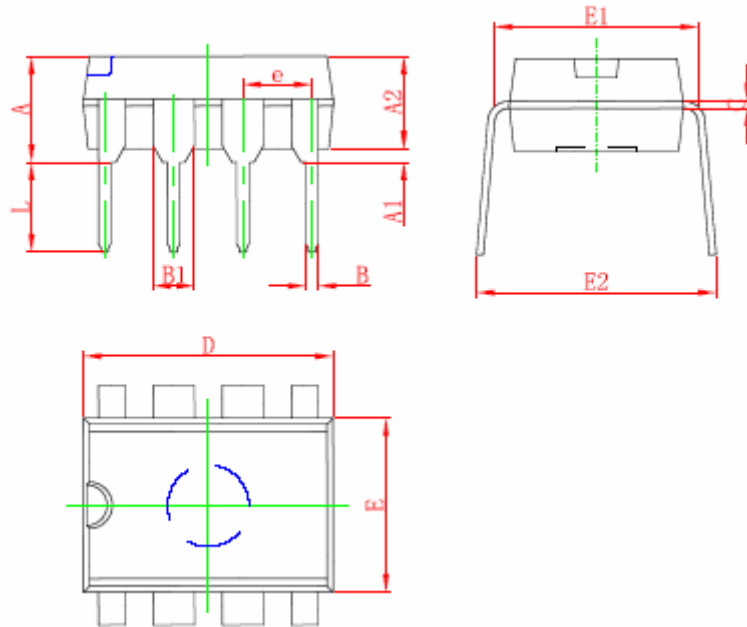
Power MOS is integrated in FT838MBD/FT838MDD for low cost and/or space limited applications, respectively.

Output cable compensation

The output cable compensation provides a constant output voltage at the end of the cable over the entire load range in constant voltage mode. As the converter load increases from no-load to the peak current load, the voltage drop introduced across the output cable is compensated by increasing the feedback pin reference voltage.

PACKAGE INFORMATION

DIP8 Package



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 3.710 | 4.310 | 0.146 | 0.170 |
| A1 | 0.510 | | 0.020 | |
| A2 | 3.200 | 3.600 | 0.126 | 0.142 |
| B | 0.380 | 0.570 | 0.015 | 0.022 |
| B1 | 1.524 (BSC) | | 0.060 (BSC) | |
| C | 0.204 | 0.360 | 0.008 | 0.014 |
| D | 9.000 | 9.400 | 0.354 | 0.370 |
| E | 6.200 | 6.600 | 0.244 | 0.260 |
| E1 | 7.320 | 7.920 | 0.288 | 0.312 |
| e | 2.540 (BSC) | | 0.100 (BSC) | |
| L | 3.000 | 3.600 | 0.118 | 0.142 |
| E2 | 8.400 | 9.000 | 0.331 | 0.354 |



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